

Title of Change:	Changing wire bond from 0.8 mil Au to 0.8 mil Pd-coated Cu for JFETs assembled in SOT-23, mold compound change from Hitachi GE200F to Hysol GR640HV Increasing top metal thickness to 20KA support this change as well		
Proposed Changed Material First Ship Date:	14 Jul 2022 or earlier if approved by customer		
Current Material Last Order Date:	14 Apr 2022 Orders received after the Current Material Last Order Date expiration are to be considered as orders for new changed material as described in this PCN. Orders for current (unchanged, material after this date will be per mutual agreement and current material inventory availability.		
Current Material Last Delivery Date:	13 Jul 2022 The Current Material Last Delivery Date may be subject to change based on build and depletio of the current (unchanged) material inventory		
Product Category:	Active components – Discrete components		
Contact information:	Contact your local onsemi Sales Office or Andy.Tao@onsemi.com		
PCN Samples Contact:	Contact your local onsemi Sales Office to place sample order. Sample requests are to be submitted no later than 45 days after publication of this change notification. Samples delivery timing will be subject to request date, sample quantity and special custome packing/label requirements.		
Sample Availability Date:	31 Jan 2022		
PPAP Availability Date:	31 Jan 2022		
Additional Reliability Data:	Contact your local onsemi Sales Office or c.l.yang@lps.com.cn		
Type of Notification:	This is a Final Product/Process Change Notification (FPCN) sent to customers. The change will be implemented at 'Proposed Change Material First Ship Date' in compliance to J-STD-46 or ZVEI, or earlier upon customer approval, or per our signed agreements. onsemi will consider this proposed change and it's conditions acceptable, unless an inquiry is made in writing within 45 days of delivery of this notice. To do so, contact <u>PCN.Support@onsemi.com</u> .		
Change Category			
Category	Type of Change		
Bare Die	New / change of frontside metallization		
Process - Assembly	Change mold compound		
Process - Assembly	Change of wire bonding		

Description and Purpose:

onsemi is notifying customers of its use of 0.8 mils Pd-coated Cu wire for JFET devices assembled in SOT-23, mold compound change from Hitachi GE200F HWG to Hysol GR640HV at onsemi Leshan, China facilityThe change requires wafer top metal thickness increase from 15 KÅ AlSi to 20 KÅ AlSi. Upon the expiration of this PCN, these devices will be built with 0.8 mils Pd-coated Cu wire and will use the thicker top at the same site. Datasheet specifications and product electrical performance remain unchanged. Reliability Qualification and full electrical characterization over temperature has been performed.

	Before Change Description	After Change Description
Bond Wire	0.8 mils Au wire	0.8 mils PD-coated Cu wire
Wafer top metal	15KA AlSi	20KA AlSi
Mold compound	Hitachi GE200F HWG	Hysol GR640HV

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Reason / Motivation for Change:		Process/Materials Change					
Anticipated impact on fit, form, function, reliability, product safety or manufacturability:		The device has been qualified and validated based on the same Product Specification. The device has successfully passed the qualification tests. Potential impacts can be identified, but due to testing performed by onsemi in relation to the PCN, associated risks are verified and excluded. No anticipated impacts.					
ites Affected:		no unicipe					
onsemi Sites				External Foundry/Subcon	Sites		
Leshan Phoenix Semiconductor, China			None				
onsemi Roznov, Czech Republic							
Marking of Parts/ Traceability of existing		existing Les	piration of this PCN devices will be assembled with 0.8 mils PD-coated Cu wire at onsemi eshan facility. Products assembled with 0.8 mils PD-coated Cu wire from the onsemi facility w nish Goods Date Code of WW24 2022 or greater.				
eliability Dat V DEVICE NAN MS: 79236	a Summary: IE : SMMBFJ177LT1G						
ACKAGE: SOT2		o n		Condition	Intorval	Results	
Test HTRB	Specificatio		Ta=150°C 100	% max rated V	1008 hrs	0/231	
HTGB	JESD22-A108				1008 hrs	0/231	
HTSL	JESD22-A108 JESD22-A103		Ta=150°C, 100% max rated Vgss Ta=150°C		2016 hrs	0/231	
MIL-STD-			Ta=+25°C, delta Tj=100°C On/off = 2 min		2010 1113	0/231	
IOL	(M1037) AEC-Q101				30К сус		
TC	JESD22-A104		Ta= -65°C to +	150°C	2000 cyc	0/231	
HAST	JESD22-A110		130°C, 85% RH, 18.8psig, bias		192 hrs	0/231	
uHAST	JESD22-A118		130°C, 85% RH	130°C, 85% RH, 18.8psig, unbiased		0/231	
	J-STD-020 JESD-A113			MSL 1 @ 260 °C	-	-	
PC	J-21D-020 JE2L	JESD22- B106		Ta = 265C, 10 sec			
				Ta = 265C, 10 sec	-	0/30	
РС		.06		Ta = 265C, 10 sec Ta = 245C, 5 sec	-	0/30 0/30	
PC RSH SD	JESD22- B1 JSTD002 IE : SMMBF4393LT1G	06			- - Interval	-	
PC RSH SD V DEVICE NAM MS: 79238 ACKAGE: SOT2	JESD22- B1 JSTD002 IE : SMMBF4393LT1G 3	06 n	Ta=150°C, 100%	Ta = 245C, 5 sec Condition	- - - Interval 1008 hrs	0/30	
PC RSH SD V DEVICE NAM MS: 79238 ACKAGE: SOT2 Test	JESD22- B1 JSTD002 IE : SMMBF4393LT1G 3 Specificatio	06 n 8	,	Ta = 245C, 5 sec Condition		0/30 Results	
PC RSH SD V DEVICE NAM MS: 79238 ACKAGE: SOT2 Test HTRB	JESD22- B1 JSTD002 IE : SMMBF4393LT1G 3 Specificatio JESD22-A10	06 n 8 8	,	Ta = 245C, 5 sec Condition	1008 hrs	0/30 Results 0/77	
PC RSH SD V DEVICE NAM MS: 79238 ACKAGE: SOT2 Test HTRB HTRB	JESD22- B1 JSTD002 IE : SMMBF4393LT1G 3 Specificatio JESD22-A10 JESD22-A10	06 n 8 8 3	Ta=150°C, 100% Ta=150°C	Ta = 245C, 5 sec Condition 5 max rated V 5 max rated Vgss	1008 hrs 1008 hrs	0/30 Results 0/77 0/77	
PC RSH SD V DEVICE NAM MS: 79238 ACKAGE: SOT2 Test HTRB HTRB	JESD22- B1 JSTD002 IE : SMMBF4393LT1G 3 Specificatio JESD22-A10 JESD22-A10 JESD22-A10	06 n 8 8 3	Ta=150°C, 100% Ta=150°C Ta=+25°C, delta	Ta = 245C, 5 sec Condition 5 max rated V 5 max rated Vgss	1008 hrs 1008 hrs	0/30 Results 0/77 0/77	
PC RSH SD V DEVICE NAM MS: 79238 ACKAGE: SOT2 Test HTRB HTGB HTGB HTSL	JESD22- B1 JSTD002 IE : SMMBF4393LT1G 3 Specificatio JESD22-A10 JESD22-A10 MIL-STD-75	06 n 8 8 3 0	Ta=150°C, 100% Ta=150°C	Ta = 245C, 5 sec Condition 5 max rated V 5 max rated Vgss	1008 hrs 1008 hrs 2016 hrs	0/30 Results 0/77 0/77 0/77	
PC RSH SD V DEVICE NAM MS: 79238 ACKAGE: SOT2 Test HTRB HTGB HTGB HTSL	JESD22- B1 JSTD002 IE : SMMBF4393LT1G 3 Specificatio JESD22-A10 JESD22-A10 JESD22-A10 MIL-STD-75 (M1037)	06 n 8 8 3 0	Ta=150°C, 100% Ta=150°C Ta=+25°C, delta	Ta = 245C, 5 sec Condition 5 max rated V 5 max rated Vgss Tj=100°C	1008 hrs 1008 hrs 2016 hrs	0/30 Results 0/77 0/77 0/77	
PC RSH SD V DEVICE NAM MS: 79238 ACKAGE: SOT2 Test HTRB HTRB HTGB HTSL IOL	JESD22- B1 JSTD002 IE : SMMBF4393LT1G 3 Specificatio JESD22-A10 JESD22-A10 JESD22-A10 MIL-STD-75 (M1037) AEC-Q101	06 n 8 8 3 0 4	Ta=150°C, 100% Ta=150°C Ta=+25°C, delta On/off = 2 min	Ta = 245C, 5 sec Condition 5 max rated V 5 max rated Vgss Tj=100°C 50°C	1008 hrs 1008 hrs 2016 hrs 30K cyc	0/30 Results 0/77 0/77 0/77 0/77	
PC RSH SD V DEVICE NAM MS: 79238 ACKAGE: SOT2 Test HTRB HTGB HTGB HTSL IOL	JESD22- B1 JSTD002 IE : SMMBF4393LT1G 3 Specificatio JESD22-A10 JESD22-A10 MIL-STD-75 (M1037) AEC-Q101 JESD22-A10	06 n 8 8 3 0 4 0	Ta=150°C, 100% Ta=150°C Ta=+25°C, delta On/off = 2 min Ta= -65°C to +15 130°C, 85% RH,	Ta = 245C, 5 sec Condition 5 max rated V 5 max rated Vgss Tj=100°C 50°C	1008 hrs 1008 hrs 2016 hrs 30K cyc 2000 cyc	0/30 Results 0/77 0/77 0/77 0/77 0/77	
PC RSH SD V DEVICE NAM MS: 79238 ACKAGE: SOT2 Test HTRB HTGB HTGB HTSL IOL IOL	JESD22- B1 JSTD002 IE : SMMBF4393LT1G 3 Specificatio JESD22-A10 JESD22-A10 MIL-STD-75 (M1037) AEC-Q101 JESD22-A10 JESD22-A10	06 n 8 8 3 0 4 0 8	Ta=150°C, 100% Ta=150°C Ta=+25°C, delta On/off = 2 min Ta= -65°C to +15 130°C, 85% RH,	Ta = 245C, 5 sec Condition 5 max rated V 5 max rated Vgss Tj=100°C 50°C 18.8psig, bias	1008 hrs 1008 hrs 2016 hrs 30K cyc 2000 cyc 192 hrs	0/30 Results 0/77 0/77 0/77 0/77 0/77 0/77	
PC RSH SD V DEVICE NAM MS: 79238 ACKAGE: SOT2 Test HTRB HTGB HTGB HTSL IOL IOL TC HAST UHAST	JESD22- B1 JSTD002 IE : SMMBF4393LT1G 3 Specificatio JESD22-A10 JESD22-A10 JESD22-A10 MIL-STD-75 (M1037) AEC-Q101 JESD22-A10 JESD22-A11 JESD22-A11	06 n 8 8 3 0 4 0 8 -A113	Ta=150°C, 100% Ta=150°C Ta=+25°C, delta On/off = 2 min Ta= -65°C to +15 130°C, 85% RH,	Ta = 245C, 5 sec Condition 5 max rated V 5 max rated Vgss Tj=100°C 18.8psig, bias 18.8psig, unbiased	1008 hrs 1008 hrs 2016 hrs 30K cyc 2000 cyc 192 hrs	0/30 Results 0/77 0/77 0/77 0/77 0/77 0/77	

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Final Product/Process Change Notification Document #:FPCN24342ZA Issue Date:05 Jan 2022

NOTE: AEC 1 Pager are attached.

To view attachments:

- 1. Download pdf copy of the PCN to your computer
- 2. Open the downloaded pdf copy of the PCN
- 3. Click on the paper clip icon available on the menu provided in the left/bottom portion of the screen to reveal the Attachment field
- 4. Then click on the attached file.

Electrical Characteristics Summary:

Full characterization and ESD performance meet datasheet specification. Detail of electrical characterization result is available upon request.

Electrical characteristics are not impacted.

List of Affected Parts:

Note: Only the standard (off the shelf) part numbers are listed in the parts list. Any custom parts affected by this PCN are shown in the customer specific PCN addendum in the PCN email notification, or on the **PCN Customized Portal**.

Current Part Number	New Part Number	Qualification Vehicle
SMMBFJ310LT3G	N/A	SMMBF4393LT1G
SMMBFJ310LT1G	N/A	SMMBF4393LT1G